MOSFET – Power, Single N-Channel 40 V, 2.8 mΩ, 110 A

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- LFPAK4 Package, Industry Standard
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V_{DSS}	40	V
Gate-to-Source Voltage	Э		V _{GS}	±20	V
Continuous Drain Current Raic	Steady State	T _C = 25°C	I _D	110	Α
(Notes 1, 3)	State	T _C = 100°C		81	
Power Dissipation		T _C = 25°C	P_{D}	68	W
R _{θJC} (Note 1)		T _C = 100°C		34	
Continuous Drain Current R _{0JA}	Steady State	T _A = 25°C	I _D	27	Α
(Notes 1, 2, 3)	State	T _A = 100°C	1	19	
Power Dissipation		T _A = 25°C	P_{D}	3.7	W
R _{θJA} (Notes 1, 2)		T _A = 100°C	1	1.6	
Pulsed Drain Current $T_A = 25^{\circ}C$, $t_p = 10 \mu s$			I _{DM}	740	Α
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to + 175	°C
Source Current (Body Diode)			I _S	76	Α
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 7 A)			E _{AS}	215	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	2.2	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	

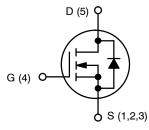
- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
- Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



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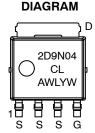
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX	
40 V	2.8 m Ω @ 10 V	110 A	
40 V	4.4 mΩ @ 4.5 V	HUA	



N-CHANNEL MOSFET



LFPAK4 CASE 760AB



MARKING

2D9N04CL = Specific Device Code A = Assembly Location

WL = Wafer Lot Y = Year W = Work Week

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

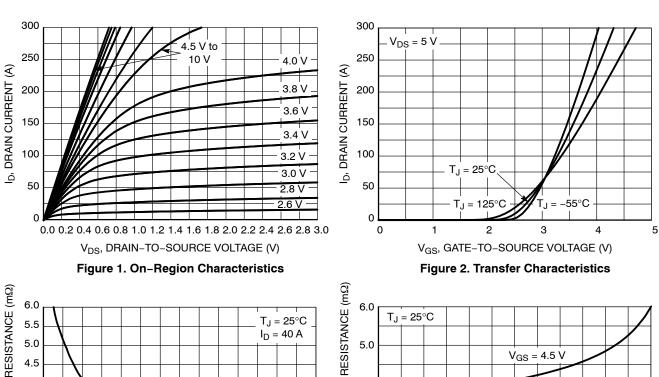
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 250 μA		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /				1.6		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25 °C			10	μΑ
		$V_{DS} = 40 \text{ V}$	T _J = 125°C			250	1
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{G}$	_S = 20 V			100	nA
ON CHARACTERISTICS (Note 4)					-		
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{DS}$) = 60 μΑ	1.2		2.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.3		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V	I _D = 40 A		3.5	4.4	
		V _{GS} = 10 V	I _D = 40 A		2.3	2.8	mΩ
Forward Transconductance	9 _{FS}	V _{DS} =15 V, I _I	_O = 40 A		120		S
CHARGES, CAPACITANCES & GATE RE	SISTANCE			•		•	•
Input Capacitance	C _{ISS}				2100		
Output Capacitance	Coss	V _{GS} = 0 V, f = 1 MH	Hz, V _{DS} = 20 V		1000		рF
Reverse Transfer Capacitance	C _{RSS}				42		1 !
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 20 V; I _D = 40 A			16		nC
Total Gate Charge	Q _{G(TOT)}				35		
Threshold Gate Charge	Q _{G(TH)}				4.0		nC
Gate-to-Source Charge	Q _{GS}	V _{GS} = 10 V, V _{DS} = 2	20 V; I _D = 40 A		7.0		
Gate-to-Drain Charge	Q_{GD}				5.0		
Plateau Voltage	V_{GP}				3.2		V
SWITCHING CHARACTERISTICS (Note	5)			•	•	•	•
Turn-On Delay Time	t _{d(ON)}				11		
Rise Time	t _r	V _{GS} = 4.5 V, V _[ne = 20 V.		110		1
Turn-Off Delay Time	t _{d(OFF)}	$I_D = 40 \text{ A}, R_G = 1 \Omega$			21		ns
Fall Time	t _f				5.0		
DRAIN-SOURCE DIODE CHARACTERIS	STICS			1		1	
Forward Diode Voltage	V_{SD}	V _{GS} = 0 V,	T _J = 25°C		0.84	1.2	
		I _S = 40 A	T _J = 125°C		0.72		V
Reverse Recovery Time	t _{RR}	V_{GS} = 0 V, dIs/dt = 100 A/ μ s, I_S = 40 A			41		
Charge Time	ta				19		ns
Discharge Time	t _b				22		1
Reverse Recovery Charge	Q _{RR}				31		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$.

5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



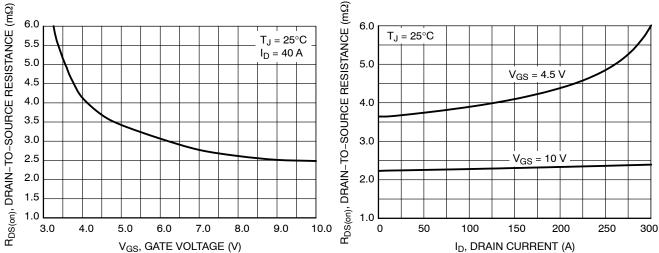


Figure 3. On-Resistance vs. Gate-to-Source

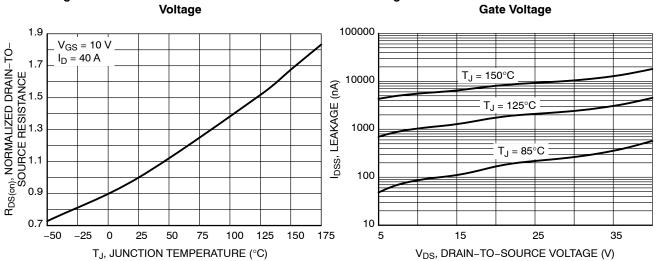
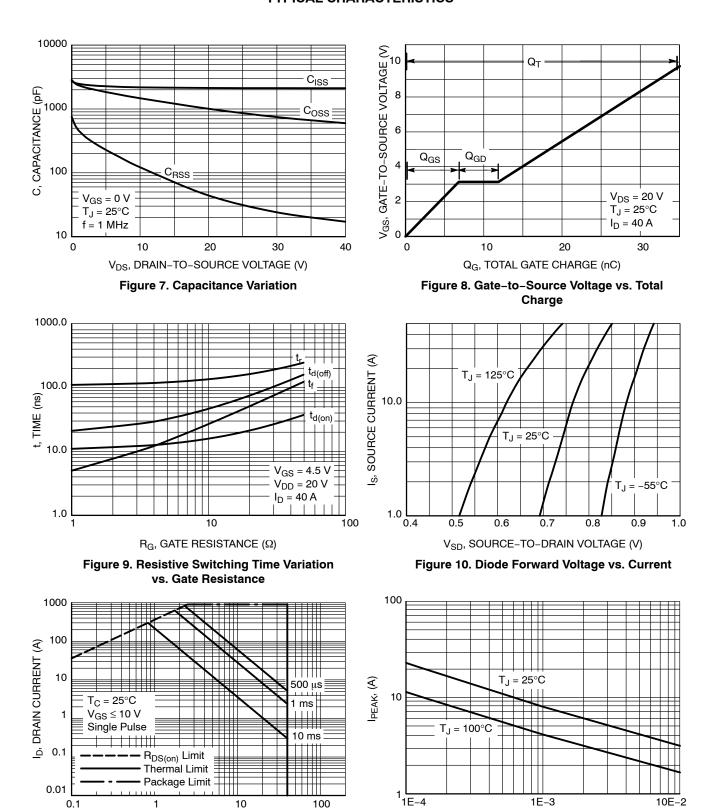


Figure 4. On-Resistance vs. Drain Current and

TYPICAL CHARACTERISTICS



 $V_{DS}\left(V\right)$ Figure 11. Safe Operating Area

 $\label{eq:TIME IN AVALANCHE (s)}$ Figure 12. IpEAK vs. Time in Avalanche

TYPICAL CHARACTERISTICS

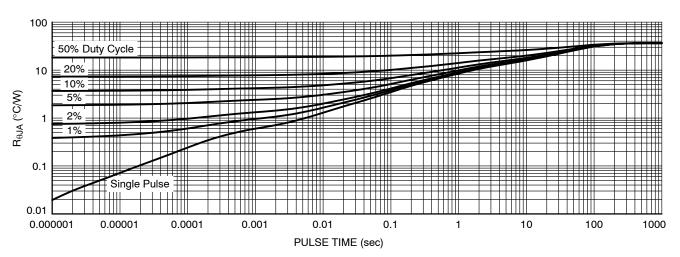


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMYS2D9N04CLTWG	2D9N04CL	LFPAK4 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

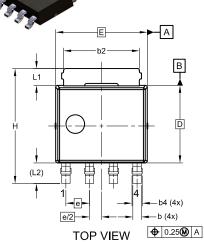


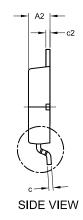
LFPAK4 4.90x4.15x1.15MM, 1.27P CASE 760AB

ISSUE D

1.30

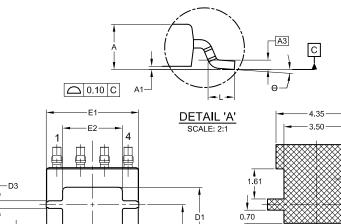
DATE 22 MAY 2024





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
- 4. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.



D4

(D8)

-	1.61
1	0.70
	↑
,	1.15
	0.70 - - 1.27 -
	RECOMMENDED LAND PATTERN
	*FOR ADDITIONAL INFORMATION ON OUR
	PB-FREE STRATEGY AND SOLDERING
	I B THEE OH WILLIAM GOLDLINIA

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*

BOTTOM VIEW

D5

D6 (D7)

XXXXXX XXXXXX AWLYW XXXXXX = Specific Device Code A = Assembly Location

WL = Wafer Lot Y = Year W = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Some products may not follow the Generic Marking.

DIM MIN NOM MAX A 1.10 1.20 1.30 A1 0.00 0.08 0.15 A2 1.10 1.15 1.20 A3 0.25 BSC 0.50 b 0.40 0.45 0.50 b2 3.80 4.10 4.40 b4 0.45 0.55 0.65 c 0.19 0.22 0.25 c2 0.19 0.22 0.25 D 4.15 BSC 0.20 0.25 D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 <td< th=""><th colspan="7">MILLIMETER</th></td<>	MILLIMETER						
A1 0.00 0.08 0.15 A2 1.10 1.15 1.20 A3 0.25 BSC b 0.40 0.45 0.50 b2 3.80 4.10 4.40 b4 0.45 0.55 0.65 c 0.19 0.22 0.25 c2 0.19 0.22 0.25 D 4.15 BSC D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2<	DIM MIN NOM MAX						
A2 1.10 1.15 1.20 A3 0.25 BSC b 0.40 0.45 0.50 b2 3.80 4.10 4.40 b4 0.45 0.55 0.65 c 0.19 0.22 0.25 c2 0.19 0.22 0.25 D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00	Α	1.10	1.20	1.30			
A3	A1	0.00	0.08	0.15			
b 0.40 0.45 0.50 b2 3.80 4.10 4.40 b4 0.45 0.55 0.65 c 0.19 0.22 0.25 c2 0.19 0.22 0.25 D 4.15 BSC D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF B8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF	A2	1.10	1.15	1.20			
b2 3.80 4.10 4.40 b4 0.45 0.55 0.65 c 0.19 0.22 0.25 c2 0.19 0.22 0.25 D 4.15 BSC D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0	Α3	().25 BSC				
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C 0.19 0.22 0.25 c2 0.19 0.22 0.25 D 4.15 BSC D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00	b2	3.80	4.10	4.40			
C2 0.19 0.22 0.25 D 4.15 BSC D1 3.80 4.00 4.20 D2 3.00 3.10 3.20 D3 0.30 0.40 0.50 D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF 1.10 REF	b4		0.55				
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D4 0.90 1.00 1.10 D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	D2	3.00	3.10	3.20			
D5 0.70 0.80 0.90 D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	D3	0.30	0.40	0.50			
D6 0.55 0.65 0.75 D7 0.31 REF D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	D4	0.90	1.00	1.10			
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D8 0.40 REF E 4.90 BSC E1 4.85 4.95 5.05 E2 3.10 3.20 3.30 E3 0.00 0.10 0.20 E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	D6	0.55	0.65	0.75			
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E4 2.00 2.10 2.20 e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	E2	3.10	3.20	3.30			
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e 1.27 BSC e/2 0.635 BSC e1 0.40 REF H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	E4			2.20			
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H 6.00 6.15 6.30 L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF	e/2						
L 0.50 0.70 0.90 L1 0.80 0.90 1.00 L2 1.10 REF							
L1 0.80 0.90 1.00 L2 1.10 REF							
L2 1.10 REF	L						
L2 1.10 REF Θ 0° 4° 8°	L1						
Θ 0° 4° 8°		1.10 REF					
	θ	0°	4°	8°			

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